

CSD16401Q5 25-V N-Channel NexFET™ Power MOSFET

1 Features

- Ultra-Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- SON 5-mm × 6-mm Plastic Package

2 Applications

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

3 Description

This 25-V, 1.3-m Ω , 5-mm × 6-mm SON NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Product Summary

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	25	V
Q_g	Gate Charge, Total (4.5 V)	21	nC
Q_{gd}	Gate Charge, Gate-to-Drain	5.2	nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 4.5\text{ V}$	1.8
		$V_{GS} = 10\text{ V}$	1.3
$V_{GS(th)}$	Threshold Voltage	1.5	V

Device Information⁽¹⁾

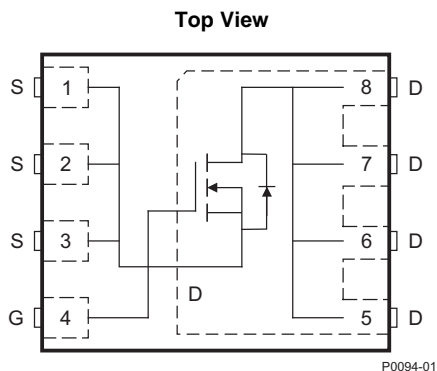
DEVICE	MEDIA	QTY	PACKAGE	SHIP
CSD16401Q5	13-Inch Reel	2500	SON 5.00-mm × 6.00-mm Plastic Package	Tape and Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

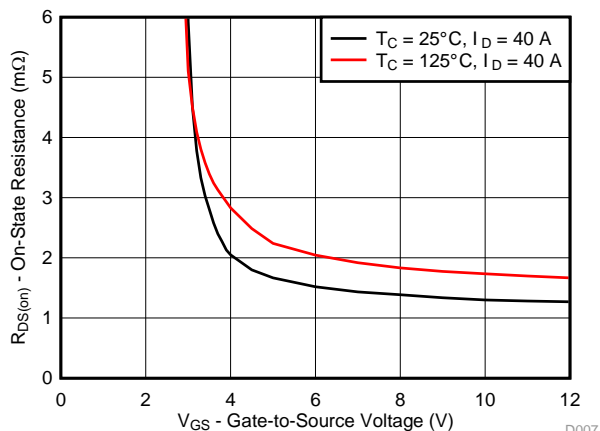
$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	25	V
V_{GS}	Gate-to-Source Voltage	-12 to 16	V
I_D	Continuous Drain Current (Package Limited)	100	A
	Continuous Drain Current (Silicon Limited), $T_C = 25^\circ\text{C}$	261	
	Continuous Drain Current ⁽¹⁾	38	
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾	240	A
P_D	Power Dissipation ⁽¹⁾	3.1	W
	Power Dissipation, $T_C = 25^\circ\text{C}$	156	
T_J, T_{stg}	Operating Junction, Storage Temperature	-55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche Energy, Single Pulse $I_D = 100\text{ A}, L = 0.1\text{ mH}, R_G = 25\ \Omega$	500	mJ

- (1) $R_{\theta JA} = 40^\circ\text{C/W}$ on 1-in² (6.45-cm²) Cu 2-oz (0.071-mm) thick on 0.06-in (1.52-mm) thick FR4 PCB.
 (2) Max $R_{\theta JC} = 0.8^\circ\text{C/W}$, pulse duration $\leq 100\ \mu\text{s}$, duty cycle $\leq 1\%$.



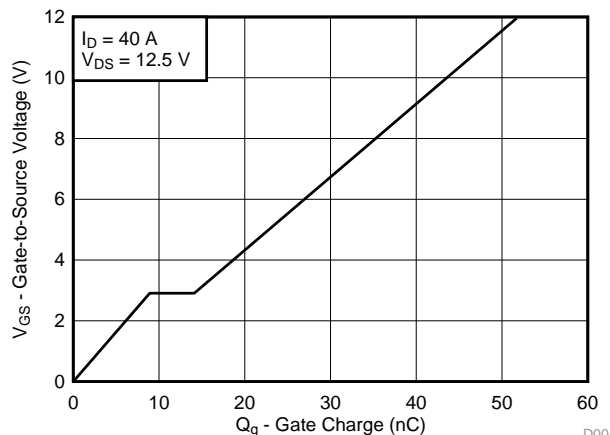
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$R_{DS(on)}$ vs V_{GS}



D007

Gate Charge



D004



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (August 2015) to Revision C Page

• Added $V_{DS} = 5\text{ V}$ to Figure 3	4
• Added <i>Receiving Notification of Documentation Updates</i> section	7

Changes from Revision A (September 2010) to Revision B Page

• Added part number to title	1
• Enhanced Description	1
• Added <i>Device and Documentation Support</i> section and <i>Mechanical, Packaging, and Orderable Information</i> section	1
• Updated pulsed current	1
• Updated Figure 1 to a normalized $R_{\theta JC}$ curve	4
• Updated the SOA in Figure 10	5

Changes from Original (August 2009) to Revision A Page

• Deleted environmental bullets from Features list	1
• Deleted <i>Package Marking Information</i> section at the end of the data sheet.....	10

5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-source voltage	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	25			V
I_{DSS}	Drain-to-source leakage current	$V_{GS} = 0\text{ V}, V_{DS} = 20\text{ V}$			1	μA
I_{GSS}	Gate-to-source leakage current	$V_{DS} = 0\text{ V}, V_{GS} = -12\text{ V to } 16\text{ V}$			100	nA
$V_{GS(th)}$	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.2	1.5	1.9	V
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 4.5\text{ V}, I_D = 40\text{ A}$		1.8	2.3	m Ω
		$V_{GS} = 10\text{ V}, I_D = 40\text{ A}$		1.3	1.6	
g_{fs}	Transconductance	$V_{DS} = 15\text{ V}, I_D = 40\text{ A}$		168		S
DYNAMIC CHARACTERISTICS						
C_{ISS}	Input capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 12.5\text{ V}, f = 1\text{ MHz}$		3150	4100	pF
C_{OSS}	Output capacitance			2530	3300	pF
C_{RSS}	Reverse transfer capacitance			175	230	pF
R_g	Series gate resistance			1.2	2.4	Ω
Q_g	Gate charge total (4.5 V)	$V_{DS} = 12.5\text{ V}, I_D = 40\text{ A}$		21	29	nC
Q_{gd}	Gate charge, gate-to-drain			5.2		nC
Q_{gs}	Gate charge, gate-to-source			8.3		nC
$Q_{g(th)}$	Gate charge at V_{th}			4.8		nC
Q_{OSS}	Output charge	$V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}$		55		nC
$t_{d(on)}$	Turnon delay time	$V_{DS} = 12.5\text{ V}, V_{GS} = 4.5\text{ V}, I_D = 40\text{ A}$ $R_G = 2\ \Omega$		16.6		ns
t_r	Rise time			30		ns
$t_{d(off)}$	Turnoff delay time			20		ns
t_f	Fall time			12.7		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode forward voltage	$I_S = 40\text{ A}, V_{GS} = 0\text{ V}$	0.85		1	V
Q_{rr}	Reverse recovery charge	$V_{DD} = 15\text{ V}, I_F = 40\text{ A}, di/dt = 300\text{ A}/\mu\text{s}$		72		nC
t_{rr}	Reverse recovery time	$V_{DD} = 15\text{ V}, I_F = 40\text{ A}, di/dt = 300\text{ A}/\mu\text{s}$		45		ns

5.2 Thermal Information

 $T_A = 25^\circ\text{C}$ (unless otherwise noted)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal resistance, junction-to-case ⁽¹⁾			0.8	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal resistance, junction-to-ambient ⁽¹⁾⁽²⁾			50	$^\circ\text{C}/\text{W}$

- (1) $R_{\theta JC}$ is determined with the device mounted on a 1-in (2.54-cm) square, 2-oz (0.071-mm) thick Cu pad on a 1.5-in \times 1.5-in (3.81-cm \times 3.81-cm), 0.06-in (1.52-mm) thick FR4 board. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- (2) Device mounted on FR4 material with 1 in² (6.45 cm²) of 2-oz (0.071-mm) thick Cu.

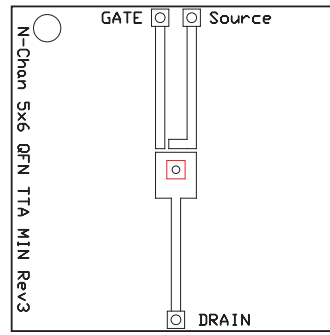
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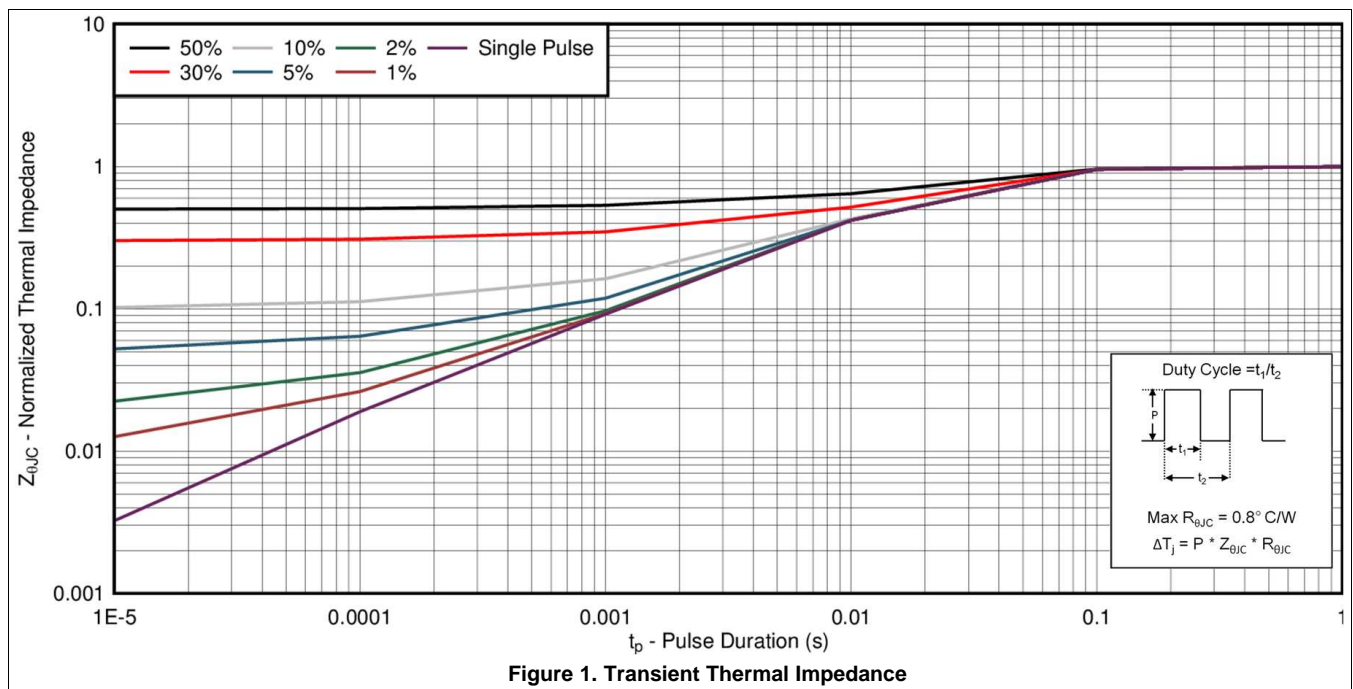
Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
when mounted on 1 in²
(6.45 cm²) of 2-oz
(0.071-mm) thick Cu.



Max $R_{\theta JA} = 125^{\circ}\text{C/W}$
when mounted on
minimum pad area of
2-oz (0.071-mm) thick
Cu.

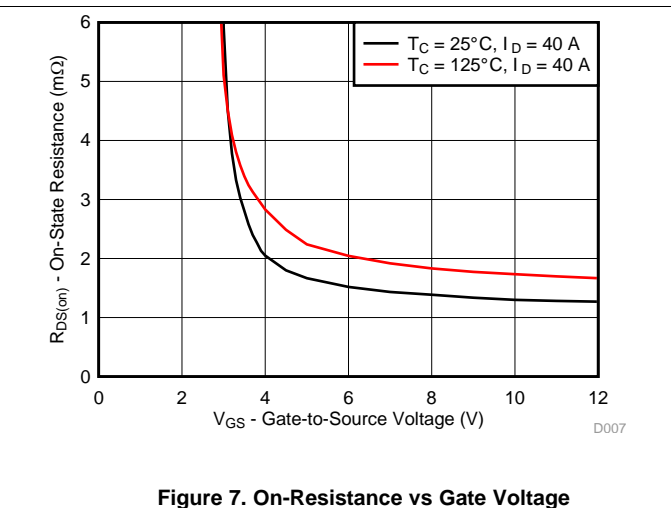
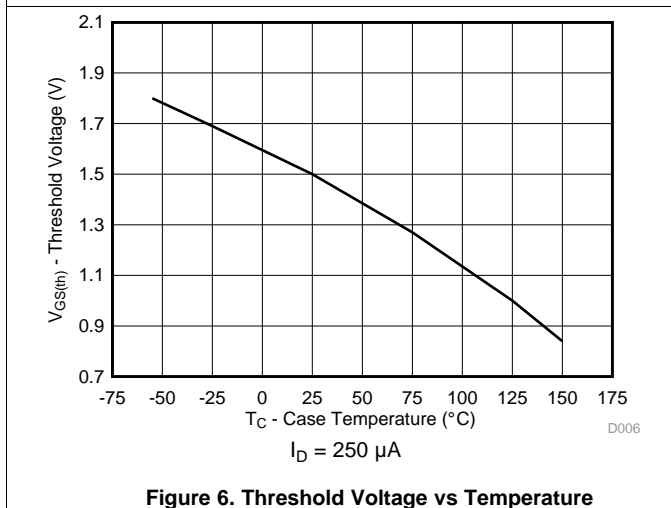
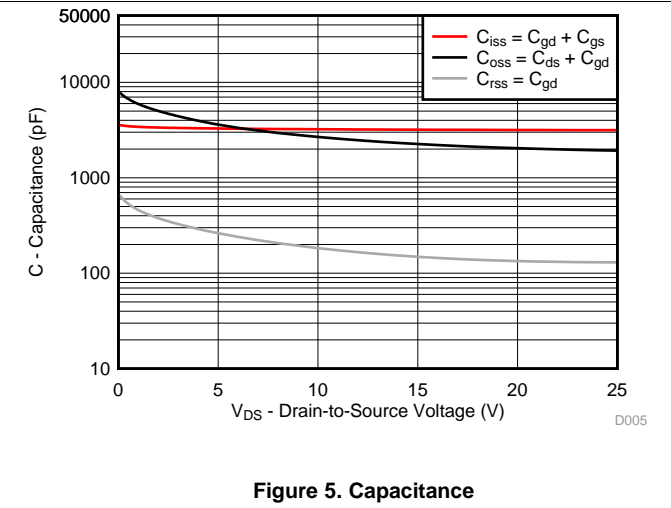
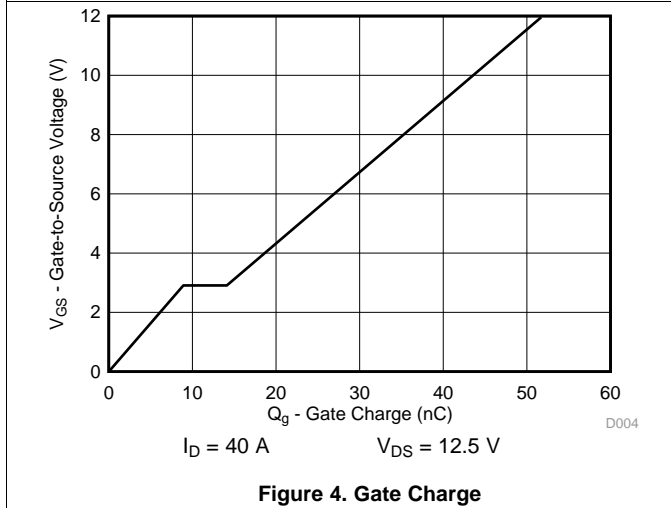
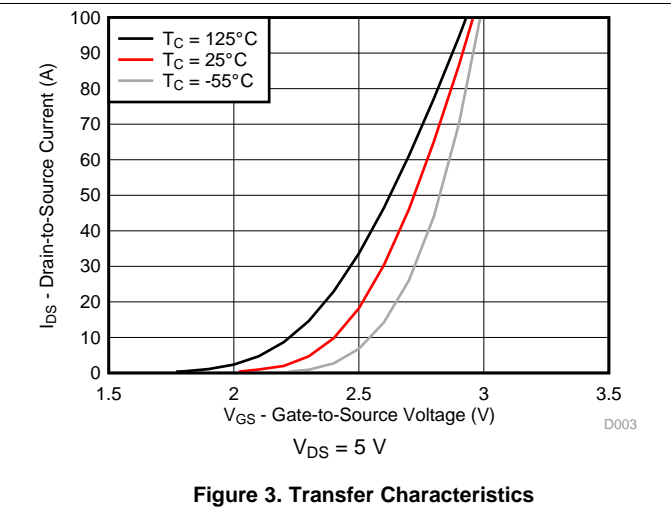
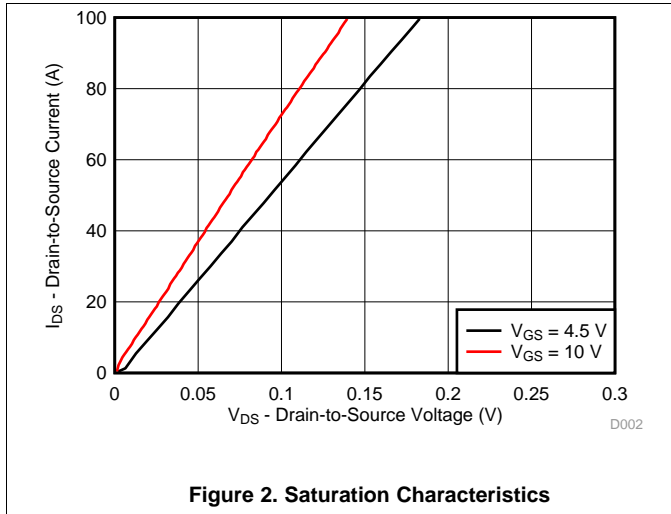
5.3 Typical MOSFET Characteristics

$T_A = 25^{\circ}\text{C}$ (unless otherwise noted)



Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise noted)



Typical MOSFET Characteristics (continued)

T_A = 25°C (unless otherwise noted)

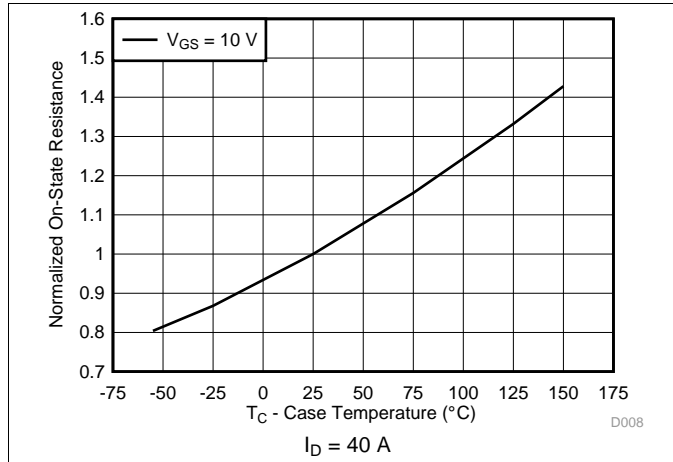


Figure 8. On-Resistance vs Temperature

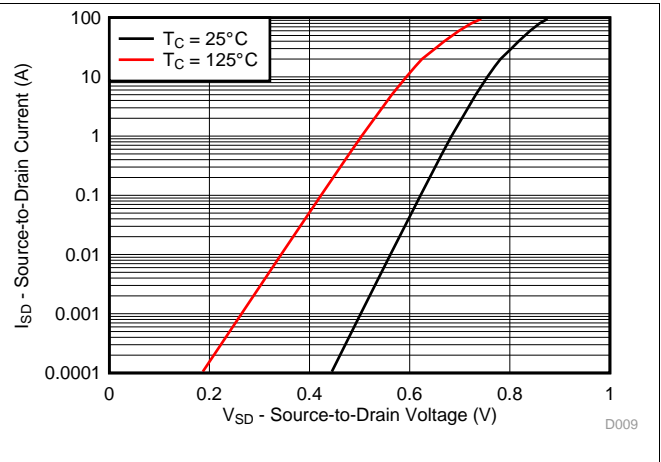


Figure 9. Typical Diode Forward Voltage

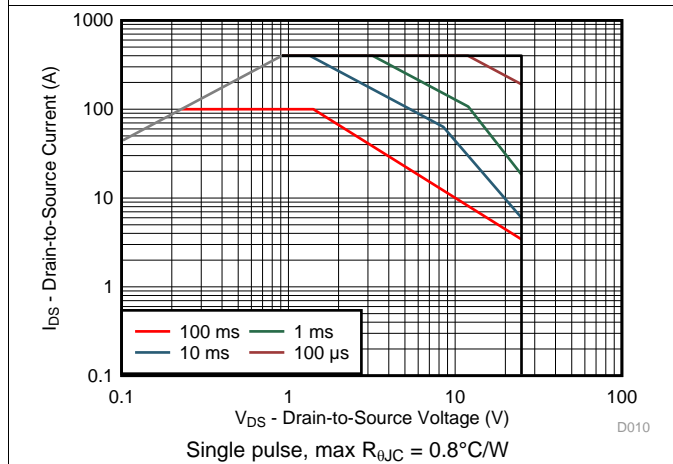


Figure 10. Maximum Safe Operating Area

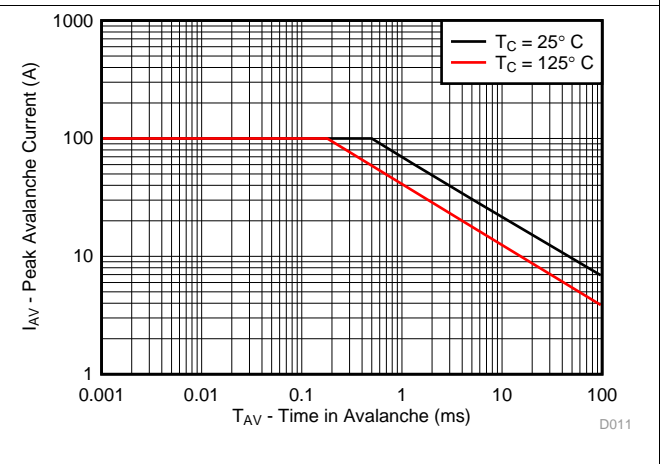


Figure 11. Single-Pulse Unclamped Inductive Switching

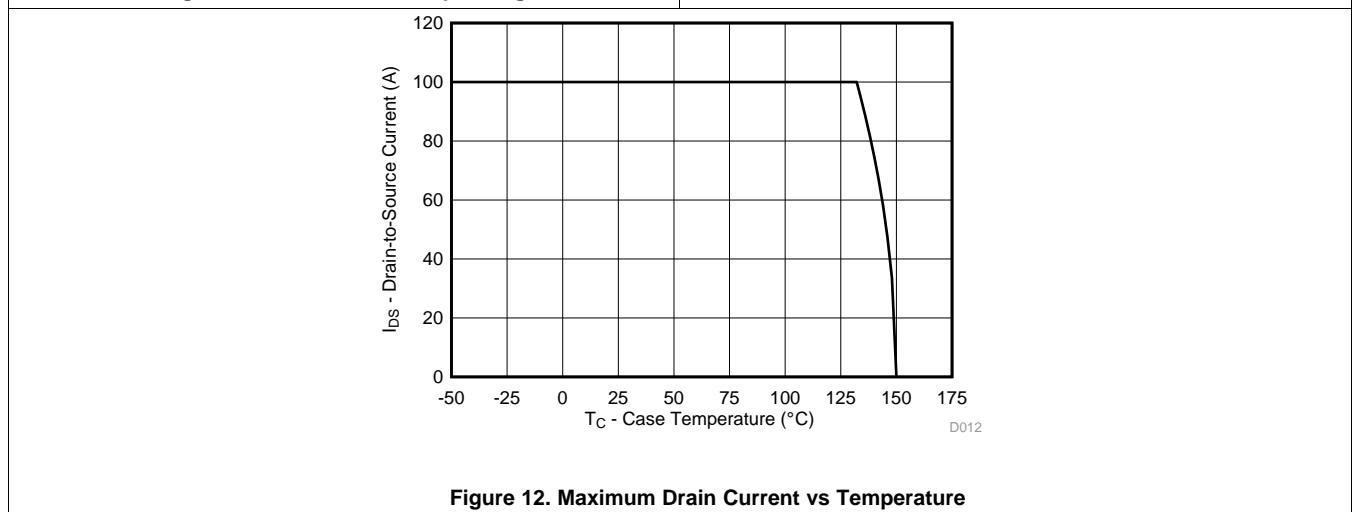


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

NexFET, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

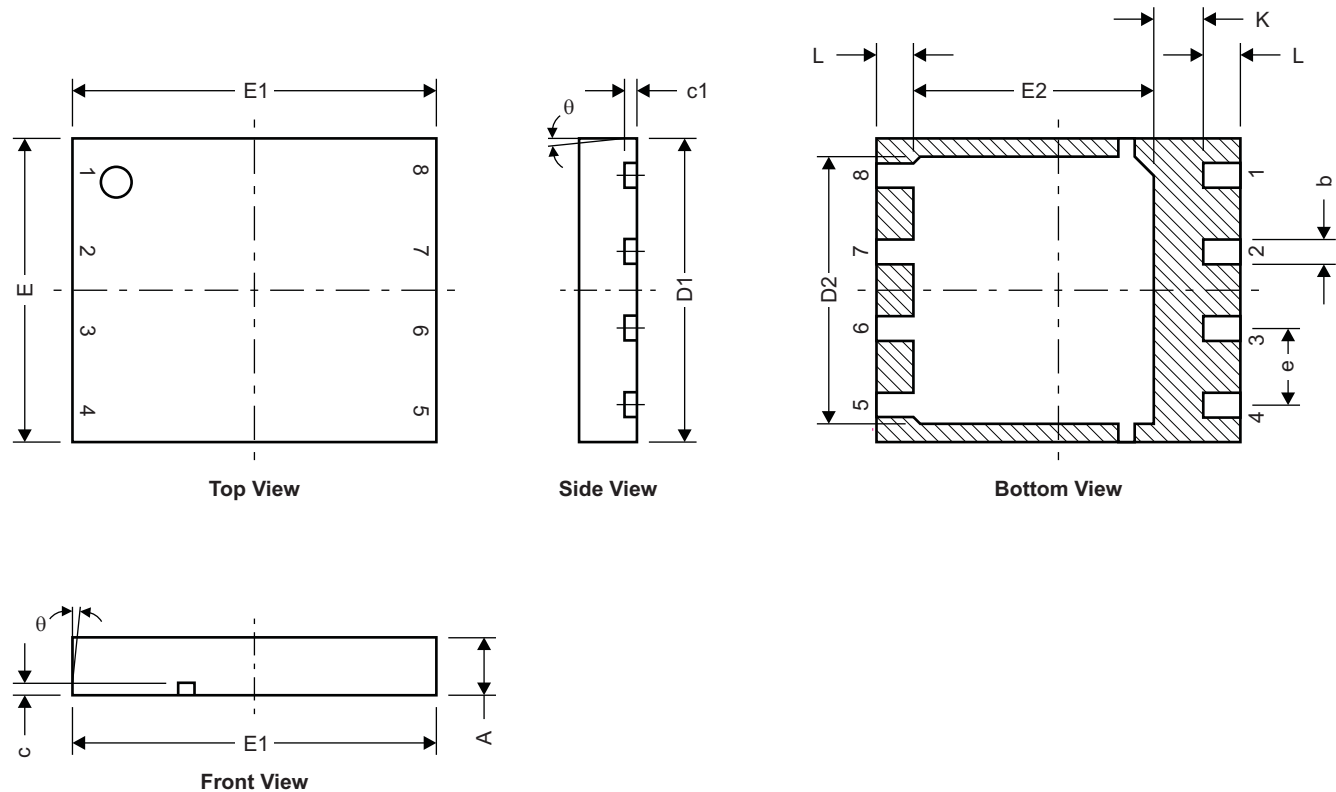
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

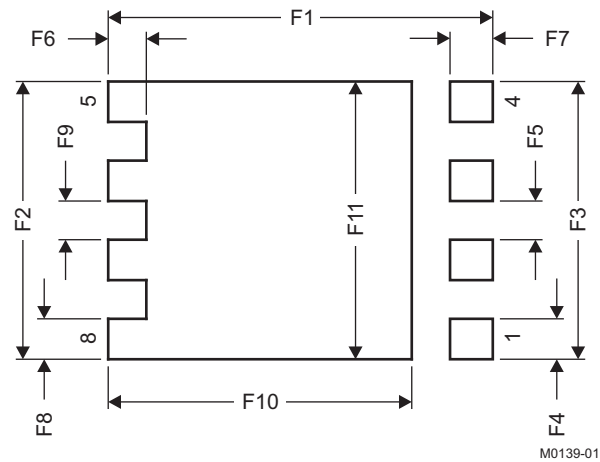
7.1 Q5 Package Dimensions



M0140-01

DIM	MILLIMETERS			INCHES		
	MIN	TYP	MAX	MIN	TYP	MAX
A	0.950		1.050	0.037		0.039
b	0.360		0.460	0.014		0.018
c	0.150		0.250	0.006		0.010
c1	0.150		0.250	0.006		0.010
D1	4.900		5.100	0.193		0.201
D2	4.320		4.520	0.170		0.178
E	4.900		5.100	0.193		0.201
E1	5.900		6.100	0.232		0.240
E2	3.920		4.12	0.154		0.162
e		1.27			0.050	
K	0.760			0.030		
L	0.510		0.710	0.020		0.028
theta	0.00					

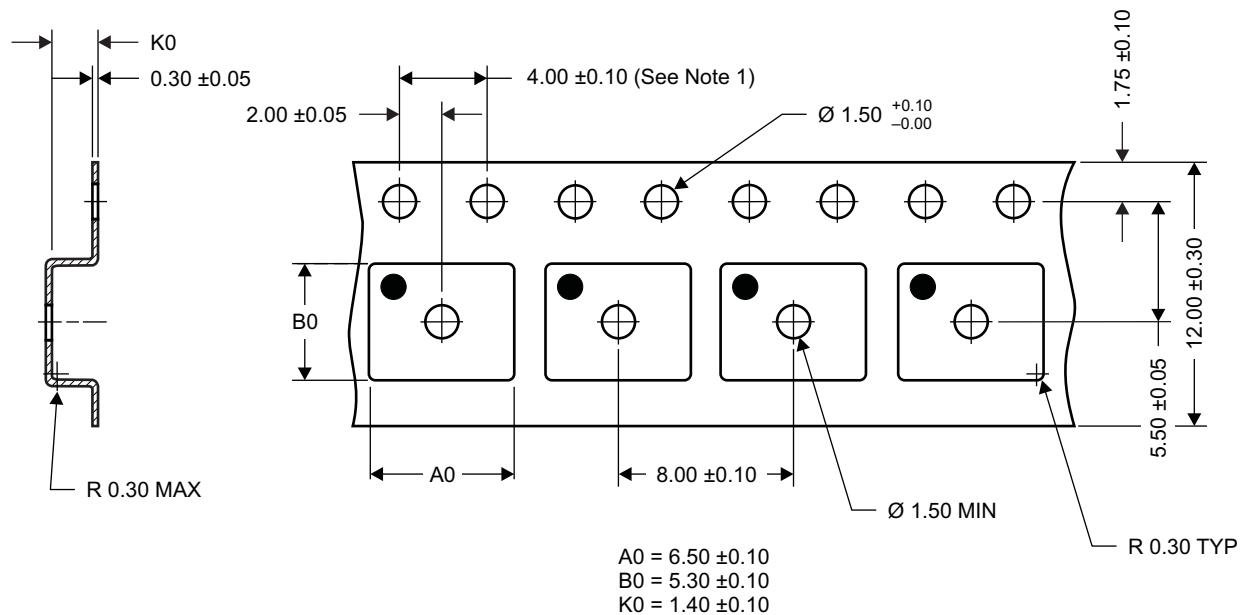
7.2 Recommended PCB Pattern



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see [Reducing Ringing Through PCB Layout Techniques \(SLPA005\)](#).

7.3 Q5 Tape and Reel Information



M0138-01

Notes:

1. 10-sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm.
3. Material: black, static-dissipative polystyrene.
4. All dimensions are in mm (unless otherwise specified).
5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket.
6. MSL1 260°C (IR and convection) PbF reflow compatible.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD16401Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16401	Samples
CSD16401Q5T	ACTIVE	VSON-CLIP	DQH	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD16401	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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